L Number	Hite	Search Text	DB	Time stamp
- Italiibei	2006	((liquid near3 crystal) or lcd) and electrode and	USPAT;	2003/06/18 13:41
:	2000	((thin near3 film) or tft) and switch\$4 and (wire or	US-PGPUB;	
!	į	wiring or circuit\$3) and reflect\$4 and (light near5	EPO; JPO;	
. 1	1	(shield\$4 or block\$4)) and substrate	DERWENT;	
		(Silicidat of blockati) and substitute	IBM TDB	
	305	240/44		2002/06/19 12:41
-	305	349/44	USPAT;	2003/06/18 13:41
1			US-PGPUB;	
į į	,		EPO; JPO;	1
ļ	:		DERWENT;	. !
1			IBM_TDB	
· -	83	(((liquid near3 crystal) or lcd) and electrode and	USPAT;	2003/06/18 13:42
j l		((thin near3 film) or tft) and switch\$4 and (wire or	US-PGPUB;	
	l	wiring or circuit\$3) and reflect\$4 and (light near5	EPO; JPO;	1
1	!	(shield\$4 or block\$4)) and substrate) and 349/44	DERWENT;	·
1			IBM_TDB	:
' -	14	((((liquid near3 crystal) or lcd) and electrode and	USPAT;	2003/06/24 07:47
!		((thin near3 film) or tft) and switch\$4 and (wire or	US-PGPUB;	:
1		wiring or circuit\$3) and reflect\$4 and (light near5	EPO; JPO;	i i
		(shield\$4 or block\$4)) and substrate) and 349/44)	DERWENT;	
		and ((electric near4 field) or e-field) and memory	IBM TDB	
<u>'</u> - '	778	((liquid near3 crystal) or lcd) and electrode and	USPAT;	2003/06/24 08:00
! ;	I	((thin near3 film) or tft) and switch\$4 and ((light	US-PGPUB;	!
	:	near5 (shield\$4 or block\$4)) and substrate) and	EPO; JPO;	!
1		reflection and transmission and ((electric near4	DERWENT;	
		field) or e-field)	IBM_TDB	
1	462	(((liquid near3 crystal) or lcd) and electrode and	USPAT;	2003/06/24 07:54
l .		((thin near3 film) or tft) and switch\$4 and ((light	US-PGPUB;	
	'	near5 (shield\$4 or block\$4)) and substrate) and	EPO; JPO;	
		reflection and transmission and ((electric near4	DERWENT;	
!	;	field) or e-field)) and 349/\$6	i IBM_TDB	: . : !
1 -	308		USPAT;	2003/06/24 08:09
	300	near3 (electrode or (electrode near3 substrate)))	US-PGPUB;	2003/00/24 00.03
		and ((thin near3 film) or tft) and switch\$4 and	EPO; JPO;	ļ
	!	(light near5 (shield\$4 or block\$4)) and reflection	DERWENT;	
,		and transmission and ((electric near4 field) or	IBM_TDB	
1	i	e-field) and ((wiring or circuit\$3) near4 (layer or	i	!
i		film or sheet))		·
-	162	(((liquid near3 crystal) or lcd) and (transparent	USPAT;	2003/06/24 08:09
	102	near3 (electrode or (electrode near3 substrate)))	US-PGPUB;	2003/00/24 08.09
' 1	!	and ((thin near3 film) or tft) and switch\$4 and	EPO; JPO;	
1		(light near5 (shield\$4 or block\$4)) and reflection	DERWENT;	
,		and transmission and ((electric near4 field) or	IBM_TDB	
		e-field) and ((wiring or circuit\$3) near4 (layer or	מטו_וטט	[
1	ĺ	film or sheet))) and 349/\$6		
1 _ ;	14 .	(((((liquid near3 crystal) or lcd) and (transparent	· · USPAT;	2003/06/24 08:18
i	177	near3 (electrode or (electrode near3 substrate)))	US-PGPUB:	2003/00/24 08:18
:	i	and ((thin near3 film) or tft) and switch\$4 and	EPO; JPO;	l į
		(light near5 (shield\$4 or block\$4)) and reflection	DERWENT;	
1		and transmission and ((electric near4 field) or	1	
	ļ	e-field) and ((wiring or circuit\$3) near4 (layer or	IBM_TDB	
:	}	film or sheet))) and 349/\$6) and (color near3	ļ	
'	:	filter)) and (molybdenum or tungsten) and	I	
į l				:
	142	(reflect\$4 near8 (aluminum or silver)) ((((liquid pear3 crystal) or led) and (transparent	LICDAT.	2002/06/24 00:45
-	142	((((liquid near3 crystal) or lcd) and (transparent	USPAT;	2003/06/24 09:45
	l	near3 (electrode or (electrode near3 substrate)))	US-PGPUB;	
	ĺ	and ((thin near3 film) or tft) and switch\$4 and	EPO; JPO;	' I
		(light near5 (shield\$4 or block\$4)) and reflection	DERWENT;	ĺ
1		and transmission and ((electric near4 field) or	IBM_TDB	
	1	e-field) and ((wiring or circuit\$3) near4 (layer or	ı	
<u> </u>	1	film or sheet))) and 349/\$6) and (color near3	, i	
		_filter)	L	

	306	349/44	USPAT; US-PGPUB;	2003/06/24 12:20
			EPO; JPO;	ļ
	! .		DERWENT;	
	!		IBM_TDB	
· -	1296	349/113	USPAT;	2003/06/24 12:20
:	ļ		US-PGPUB;	i i
:			EPO; JPO;	
			DERWENT; IBM_TDB	
_	228	349/114	USPAT;	2003/06/24 12:20
	. 220	5 + 5/11 +	US-PGPUB;	2000,00,2: 12:120
-	1		EPO; JPO;	;
	'	 -	DERWENT;	<u>.</u>
	Ì i	İ	IBM_TDB	j .
-	1052	349/110	USPAT;	2003/06/24 12:20
1			US-PGPUB;	
	Į.		EPO; JPO;	
	1	i	DERWENT;	i
:	202	: : 349/111	IBM_TDB USPAT;	: 2003/06/24 12:20
-	382	· 57 <i>5]</i> 111	US-PGPUB;	- 2003/00/24 12:20 -
			EPO; JPO;	į
			DERWENT;	
!			IBM_TDB	
; -	2631	349/44 or 349/113 or 349/114 or 349/110 or	USPAT;	2003/06/24 12:20
I		349/111	US-PGPUB;	·
1			EPO; JPO;	·
			DERWENT;	İ
į			IBM_TDB	2000/06/24 42 27
! -	59	(349/44 or 349/113 or 349/114 or 349/110 or	USPAT;	2003/06/24 12:37
i	1	349/111) and (((liquid near3 crystal) or lcd) and (transparent near3 (electrode or (electrode near3	US-PGPUB;	1
		substrate))) and ((thin near3 film) or tft) and	EPO; JPO; DERWENT;	ļ į
1		switch\$4 and (light near5 (shield\$4 or block\$4))	IBM_TDB	·
1		and reflection and transmission and ((electric)
	i	near4 field) or e-field) and ((wiring or circuit\$3)	!	
į.	•	near4 (layer or film or sheet)))	1	
! =	8	((349/44 or 349/113 or 349/114 or 349/110 or	; USPAT;	2003/06/24 14:34
1		349/111) and (((liquid near3 crystal) or lcd) and	US-PGPUB;	·
}		(transparent near3 (electrode or (electrode near3	EPO; JPO;	
	1	substrate))) and ((thin near3 film) or tft) and switch\$4 and (light near5 (shield\$4 or block\$4))	DERWENT; IBM_TDB	
1		and reflection and transmission and ((electric	: 1DM_1DD	!
1	į i	near4 field) or e-field) and ((wiring or circuit\$3)		<u> </u>
	1	near4 (layer or film or sheet)))) and (wiring near3		į
		pattern)	1	
į -	4213	umemoto.in.	USPAT;	2003/06/24 14:38
			US-PGPUB;	
			EPO; JPO;	i
	1		DERWENT;	
1 -	' a	umemoto.in. and 349/113	IBM_TDB USPAT;	2003/06/24 14:38
:		I	US-PGPUB;	: 2003/00/24 14.30 ·
			EPO; JPO;	.
1	1		DERWENT;	
!	1	!	IBM_TDB	
; -	1498	349/113	USPAT;	2003/12/23 10:00
1	ļ ;		US-PGPUB;)
]		EPO; JPO;	
1	1	1	DERWENT; IBM_TDB	
		<u>!</u>	1 100	L

US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	003/12/23 10:00
EPO; JPO; DERWENT; IBM_TDB - 1160 349/110 USPAT; 200 US-PGPUB; EPO; JPO; DERWENT; IBM_TDB - 363 349/44 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB - 2865 349/113 or 349/114 or 349/110 or 349/44 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	003/12/23 10:00
DERWENT; IBM_TDB - 1160 349/110 USPAT; 200 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB - 363 349/44 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB - 2865 349/113 or 349/114 or 349/110 or 349/44 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB - 299 (349/113 or 349/114 or 349/110 or 349/44) and USPAT; 200 - 299 (349/113 or 349/114 or 349/110 or 349/44) and USPAT; 200	003/12/23 10:00
IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; USPAT; USPAT; USPAT; USPAT; USPAT; USPAT; USPAT; USPAT; USPAT;	003/12/23 10:00
- 1160 349/110 USPAT; 200 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 200 USPAT;	003/12/23 10:00
US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; USPA	03/12/23 10:00
EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 2000 DER	
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- 363 349/44 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; US-PGPUB; EPO; JPO; DERWENT; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; USPAT	
- 363 349/44 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; ISPAT; US-PGPUB; EPO; JPO; DERWENT; ISPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 200 DERWENT; ISPATDB USPAT; 200 DERWENT; ISPATDB USPAT; 200 DERWENT; ISPAT; 200 DERWENT; 200 DERWENT; 200 DERWENT; 200 DERWENT	
US-PGPUB; EPO; JPO; DERWENT; IBM_TDB US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB EPO; JPO; DERWENT; IBM_TDB USPAT; 200 DERWENT; 200 DERWENT; 200 DERWENT; 200 DERWENT; 200 DERWENT; 200 DERWE	002112122 10.00
EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 200 DERWENT; 200 DERWENT; 200 DERWENT; 200 DERWENT; 200 DERWENT; 200 DERWENT	003/12/23 10:00
DERWENT; IBM_TDB USPAT; 20 US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 20 US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 299 (349/113 or 349/114 or 349/110 or 349/44) and USPAT; 20 USPAT; 2	
BM_TDB USPAT; 201 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; 201 USPAT;	
- 2865 349/113 or 349/114 or 349/110 or 349/44 USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB Compared to the compared to t	
US-PGPUB; EPO; JPO; DERWENT; IBM_TDB - 299 (349/113 or 349/114 or 349/110 or 349/44) and USPAT; 20	
EPO; JPO; DERWENT; IBM_TDB 299 (349/113 or 349/114 or 349/110 or 349/44) and USPAT; 20	003/12/23 10:00
DERWENT; IBM_TDB 299 (349/113 or 349/114 or 349/110 or 349/44) and USPAT; 20	
IBM_TDB	
- 299 (349/113 or 349/114 or 349/110 or 349/44) and USPAT; 20	
(reflect\$4 near8 (light near5 (shield\$4 or US-PGPUB;	003/12/23 10:03
block\$4)))	
DERWENT;	
IBM_TDB	
	003/12/23 10:02
(reflect\$4 near8 (light near5 (shield\$4 or US-PGPUB;	
block\$4)))) and (pattern near8 unmask) EPO; JPO;	
DERWENT;	
IBM_TDB	
	003/12/23 10:02
(reflect\$4 near8 (light near5 (shield\$4 or US-PGPUB;	
block\$4)))) and (pattern near8 mask\$3)	
DERWENT;	
IBM TDB	
	003/12/23 10:03
((reflect\$4 near8 (light near5 (shield\$4 or US-PGPUB;	,,
block\$4))) near9 (pattern or mask or wiring)) EPO; JPO;	
DERWENT;	
IBM_TDB	
((reflect\$4 near8 (light near5 (shield\$4 or US-PGPUB;)∩3/12/23 1 ∩ ∙∩4
block\$4))) same (pattern or mask or wiring)) EPO; JPO;	003/12/23 10:04
DERWENT;	003/12/23 10:04
IBM TDB	003/12/23 10:04